

Notice of References Cited

Application/Control No.

09/842,802

Applicant(s)/Patent Under
Reexamination
NOGUCHI ET AL.

Examiner

Matthew J Song

Art Unit

1765

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U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-5,834,803	11-1998	Nashimoto, Keiichi	257/295
	B	US-			
	C	US-			
	D	US-			
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	O					
	P					
	Q					
	R					
	S					
	T					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages
	U	Park et al. "Fabrication of PbZrTi1-xO3 Films on Si Structures Using Y2O3 Buffer layers", (1998), Jpn. J. Appl. Phys. Vol. 37 pp 5145-5149.
	V	
	W	
	X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.